

GD54/74LS132

QUAD 2-INPUT NAND GATES WITH SCHMITT TRIGGER INPUTS

Features

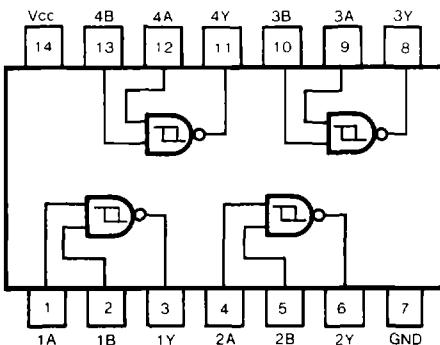
- Suitable for waveforms shaping applications
- Wide hysteresis width (0.8V typical) and high noise margin

Description

This device contains four independent gates each of which performs the logic NAND function. Each input has hysteresis which increases the noise immunity and transforms a slowly changing input signal to a fast changing, jitter free output.

When inputs A and B are high, output Y is low, and when either or both inputs are low, Y is high.

Pin Configuration



V_{IN} VERSUS V_{OUT}
TRANSFER FUNCTION

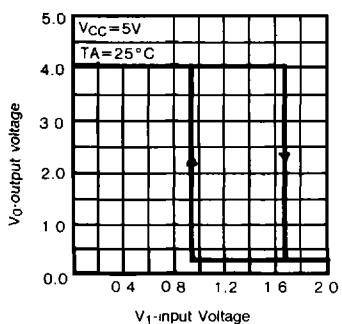


Fig. 1

Function Table

A	B	Y
L	L	H
H	L	H
L	H	H
H	H	L

Y = $\bar{A}\bar{B}$

Absolute Maximum Ratings

- Supply voltage, V_{CC} 7V
- Input voltage 7V
- Operating free-air temperature range 54LS -55°C to 125°C
- 74LS 0°C to 70°C
- Storage temperature range -65°C to 150°C

Recommended Operating Conditions

SYMBOL	PARAMETER		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	54	4.5	5	5.5	V
		74	4.75	5	5.25	
I_{OH}	High-level output current	54, 74			-400	μA
					4	
I_{OL}	Low-level output current	54			8	mA
		74				
T_A	Operating free-air temperature	54	-55		125	$^{\circ}C$
		74	0		70	

Electrical Characteristics over recommended operating free-air temperature range (unless otherwise noted)

SYMBOL	PARAMETER	TEST CONDITIONS		MIN	TYP (Note 1)	MAX	UNIT	
V_{T+}	Positive-Going Input Threshold Voltage (Note 1)	$V_{CC}=5V$		1.4	1.6	1.9	V	
V_{T-}	Negative-Going Input Threshold Voltage (Note 1)	$V_{CC}=5V$		0.5	0.8	1	V	
V_{IK}	Input clamp voltage	$V_{CC}=\text{Min}, I_I = -18mA$				-1.5	V	
V_{T+}, V_{T-}	Input Hysteresis (Note 1)	$V_{CC}=5V$		0.4	0.8		V	
V_{OH}	High-level output voltage	$V_{CC}=\text{Min}$		54	2.5	3.4	V	
		$I_{OH}=\text{Max}, V_I=V_{T-}\text{Min}$		74	2.7	3.4		
V_{OL}	Low-level output voltage	$V_{CC}=\text{Min}$	$I_{OL}=4mA$	54, 74	0.25	0.4	V	
		$V_I=V_{T+}\text{Max}$	$I_{OL}=8mA$	74	0.35	0.5		
I_{T+}	Input Current at Positive-Going Threshold	$V_{CC}=5V, V_I=V_{T+}$			-0.14		mA	
I_{T-}	Input Current at Negative-Going Threshold	$V_{CC}=5V, V_I=V_{T-}$			-0.18		mA	
I_I	Input current at maximum input voltage	$V_{CC}=\text{Max}, V_I=7V$				0.1	mA	
I_{IH}	High-level input current	$V_{CC}=\text{Max}, V_I=2.7V$				20	μA	
I_{IL}	Low-level input current	$V_{CC}=\text{Max}, V_I=0.4V$				-0.4	mA	
I_{OS}	Short-circuit output current	$V_{CC}=\text{Max}$ (Note 2)			-20	-100	mA	
I_{CCH}	Supply current	Total with outputs high	$V_{CC}=\text{Max}$			5.9	11	mA
		Total with outputs low	$V_{CC}=\text{Max}$			8.2	14	mA

Note 1. All typical values are at $V_{CC}=5V, T_A=25^{\circ}C$.

Note 2. Not more than one output should be shorted at a time, and the duration should not exceed one second.

Switching Characteristics, $V_{CC}=5V, T_A=25^{\circ}C$

SYMBOL	PARAMETER	TEST CONDITION#	MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	$C_L=15pF, R_L=2k\Omega$		15	22	ns
	Propagation delay time, high-to-low-level output			15	22	ns

#For load circuit and voltage waveforms, see page 3-11.